HSTPSC10H065BYTR

Silicon Carbide Schottky Diode

General Description

This product family offers state of the art performance. It is designed for high frequency applications where high efficiency and high reliability are required.

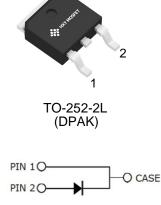
Features

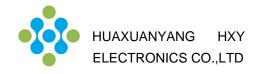
- Low conduction loss due to low VF
- Extremely low switching loss by tiny Qc
- Highly rugged due to better surge current
- Industrial standard quality and reliability

Applications

- UPS
- Power Inverter
- High performance SMPS
- Power factor correction

Ordering Part Number	Package	Qty(PCS)
HSTPSC10H065BYTR	TO-252-2L(DPAK)	2500





Silicon Carbide Schottky Diode

Maximum Ratings (at Tj = 25 °C, unless otherwise specified)

Parameter	Symbol	Value	Unit
Repetitive Peak Reverse Voltage	Vrrm	650	V
Surge Peak Reverse Voltage	Vrsm	650	V
DC Peak Reverse Voltage	VR	650	V
Continuous Forward Current Tc = 25°C Tc = 135°C Tc = 160°C	lF	30 15 10	А
Repetitive Peak Forward Surge Current Tc = 25°C,tp=10ms,Half Sine Pulse Tc = 110°C,tp=10ms,Half Sine Pulse	İFRM	45 27	А
Non-Repetitive Forward Surge Current Tc = 25°C,tp=10ms,Half Sine Pulse Tc = 110°C,tp=10ms,Half Sine Pulse	Ігѕм	80 70	А
i^2 dt value $T_C = 25^{\circ}C, t_p = 10 ms, Half Sine Pulse T_C = 110^{\circ}C, t_p = 10 ms, Half Sine Pulse$	∫ i²dt	31.7 24.3	A²s
Power dissipation $Tc = 25^{\circ}C$ $Tc = 110^{\circ}C$	Ptot	75 32	W
Operating junction Range	Tj	-55 to +175	°C
Storage temperature Range	T _{stg}	-55 to +150	°C

Thermal Resistance

Parameter	Symbol	Value	Unit
Thermal resistance, junction – case.	RthJC	2.0	°C/W



Electrical Characteristic (at Tj = 25 °C, unless otherwise specified)

Parameter	Symbol		Value		Unit	Test Condition
i arameter	Syllibol	min.	typ.	max.	Oill	rest condition
						I=10A
Forward Voltage	VF	-	1.3	1.5	V	T _j =25°C
		-	1.5	-		Tj=175°C
						Vr=650V
Reverse Current	lr	-	-	50	μΑ	T _j =25°C
		-	-	200		T _j =175°C
						V _R =400V,T _j =25℃
Total Capacitive Charge	Qc	-	28	-	nC	$Q_C = \int_0^{V_R} C(V) dV$
						Tj=25℃, f=1MHz
T		-	562	-	_	V _R =0V
Total Capacitance	С	-	56	-	pF	V _R =200V
		-	44	-		Vr=400V

Characteristics Curve:

Fig 1: Forward Characteristics

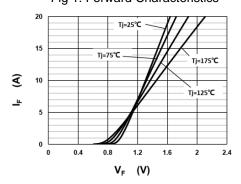
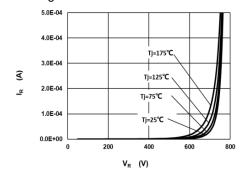


Fig 2: Reverse Characteristics



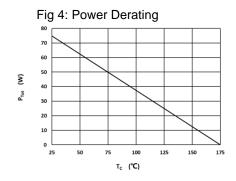




Fig 5: Capacitance vs. Reverse Voltage

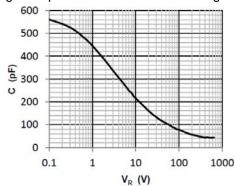


Fig 6: Reverse Charge vs. Reverse Voltage

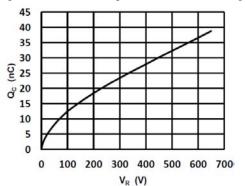


Fig 7: Typical Capacitance Stored Energy

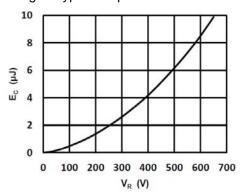
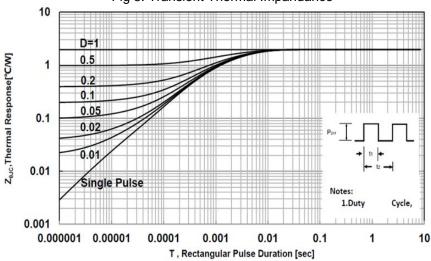


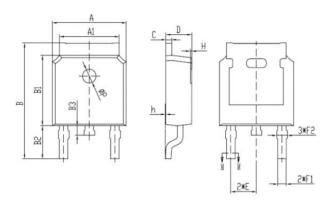
Fig 8: Transient Thermal Impandance





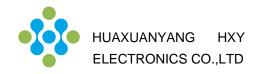
Package Dimensions

Package TO-252-2L(DPAK)





项目	规范(mm)		
	MIN	MAX	
A	6.50	6.70	
A1	5.16	5.46	
В	9.77	10.17	
B1	6.00	6.20	
B2	2.60	3.00	
B3	0.70	0.90	
С	0.45	0.61	
D	2.20	2.40	
E	2.186	2.386	
F1	0.67	0.87	
F2	0.76	0.96	
Н	0.00	0.30	
h	0.00	0.127	
L	6.50	6.70	
φР	1.10	1.30	



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